

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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OP905, OP906



Features:

- Clear epoxy package
- Linear response vs. irradiance
- Fast switching time
- Narrow receiving angle
- T-1package style
- Small package style ideal for space-limited applications



Description:

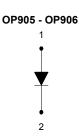
Each **OP905** and **OP906** device consists of a PIN silicon photodiode molded in a clear epoxy package that allows spectral response from visible to infrared light wavelengths. The T-1 package style is ideal for space-limited applications. Both devices have a narrow receiving angle, which provides excellent on-axis coupling. Both are also 100% production tested using infrared light for close correlation with OPTEK's GaAs and GaAiAs emitters.

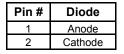
Please refer to Application Bulletins 208 and 210 for additional design information and reliability (degradation) data.

Applications:

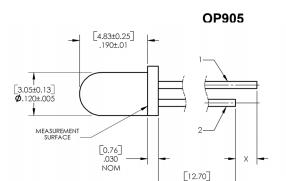
- Non-contact reflective object sensor
- Assembly line automation
- Machine automation
- Machine safety
- End of travel sensor



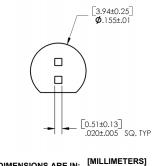




Ordering Information Part Number Sensor Viewing Angle Lead Length OP905 OP906 Photodiode 95° 0.50"

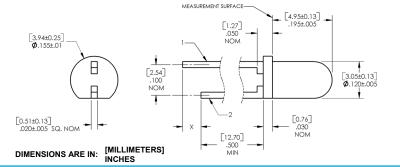


500



DIMENSIONS ARE IN:	[MILLIME INCHES

OP906



CONTAINS POLYSULFONE

To avoid stress cracking, we suggest using ND Industries' **Vibra-Tite** for thread-locking. **Vibra-Tite** evaporates fast without causing structural failure in OPTEK'S molded plastics.

General Note

TT Electronics reserves the right to make changes in product specification without notice or liability. All information is subject to TT Electronics' own data and is considered accurate at time of going to print.

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OP905, OP906



Electrical Specifications

Absolute Maximum Ratings (T _A = 25° C unless otherwise noted)				
Reverse Breakdown Voltage	60 V			
Storage & Operating Temperature Range	-40° C to +100° C			
Lead Soldering Temperature [1/16 inch (1.6mm) from the case for 5 sec. with soldering iron]	260° C ⁽¹⁾			
Reverse Breakdown Voltage	60 V			
Power Dissipation	100 mW ⁽²⁾			

Electrical Characteristics (T _A = 25° C unless otherwise noted)							
SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS	
Ι _ι	Reverse Light Current OP905 OP906	14 16	-	32 35	μА	$V_R = 5 \text{ V, } E_E = 0.50 \text{ mW/cm}^{2 (3)}$	
I _D	Reverse Dark Current	-	1	60	nA	$V_R = 30 \text{ V, } E_E = 0^{(4)}$	
V _(BR)	Reverse Breakdown Voltage	60	-	-	٧	Ι _R = 100 μΑ	
V_{F}	Forward Voltage	-	-	1.2	V	I _F = 1 mA	
Ст	Total Capacitance	-	4	-	pF	V _R = 20 V, E _E = 0, f = 1.0 MHz	
t _r	Rise Time	-	5	-	ns	$V_R = 20 \text{ V}, \lambda = 850 \text{ nm}, R_L = 50 \Omega$	
t_f	Fall Time	-	5	-			

Notes:

- (1) RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering. A maximum of 20 grams force may be applied to leads when soldering.
- (2) Derate linearly 1.67 mW/° C above 25° C.
- (3) Light source is an unfiltered GaAs LED with a peak emission wavelength of 935 nm and a radiometric intensity level which varies less than 10% over the entire lens surface of the photodiode being tested.

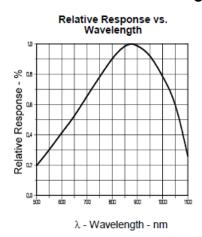
 (4) Calculate the typical dark current in nA using the formula $I_D = 10^{(0.042T_A^{-1.5})}$ where T_A is ambient temperature in °C.

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OP905, OP906



Performance OP905



Coupling Characteristics
OP905 and OP265

VR = 5 V
IF = 20 mA

Distance Between Lens Tips - inches

Reverse Voltage

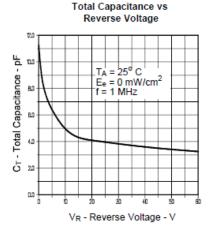
TA = 25° C

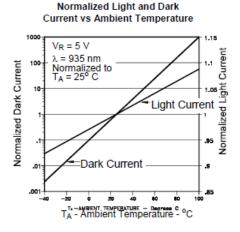
\[\lambda = 935 \text{ nm} \]

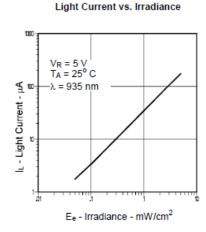
Normalized to VR = 5 V

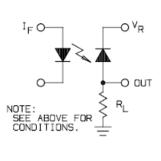
VR - Reverse Voltage - V

Normalized Light Current vs

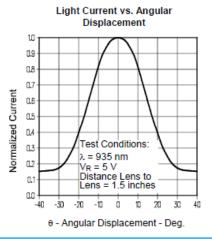








Switching Time Test Circuit



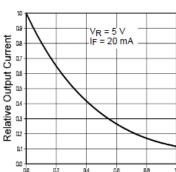
OP905, OP906



Performance OP906

Relative Response vs. Wavelength

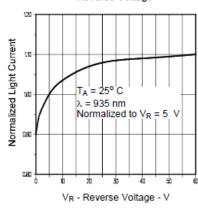
Coupling Characteristics OP906 and OP266



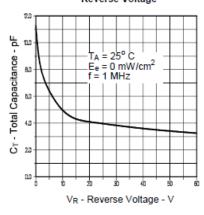
λ - Wavelength - nm

Distance Between Lens Tips -inches

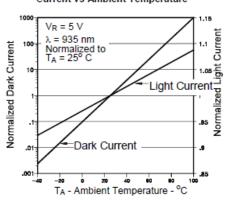
Normalized Light Current vs Reverse Voltage



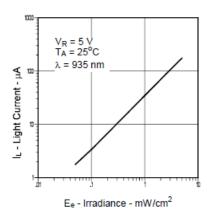
Total Capacitance vs Reverse Voltage



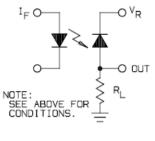
Normalized Light and Dark Current vs Ambient Temperature



Light Current vs. Irradiance



Switching Time Test Circuit



Light Current vs. Angular

